

# SHANGHAI SUNRISE ELECTRONICS CO., LTD.

## SS22A THRU SS26A

## SURFACE MOUNT SCHOTTKY **BARRIER RECTIFIER**

**TECHNICAL SPECIFICATION** 

**VOLTAGE: 20 TO 60V CURRENT: 2.0A** 

#### **FEATURES**

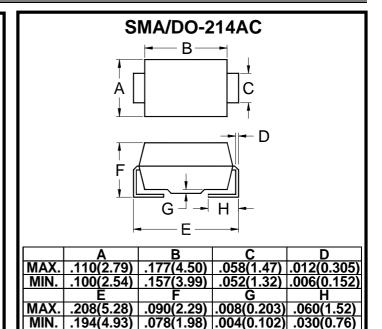
- Ideal for surface mount pick and place application
- Low profile package
- Low power loss, high efficiency
- High current capability, low V<sub>F</sub>
- High surge capability
- High temperature soldering guaranteed: 260°C/10sec/at terminal

#### MECHANICAL DATA

 Terminal: Plated leads solderable per MIL-STD 202E, method 208C

 Case: Molded with UL-94 Class V-O recognized flame retardant epoxy

Polarity: Color band denotes cathode



Dimensions in inches and (millimeters)

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	SS22A	SS23A	SS24A	SS25A	SS26A	UNITS
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	20	30	40	50	60	V
Maximum RMS Voltage	$V_{RMS}$	14	21	28	35	42	V
Maximum DC Blocking Voltage	$V_{DC}$	20	30	40	50	60	V
Maximum Average Forward Rectified Current $(T_L=100^{\circ}C)$	I <sub>F(AV)</sub>	2.0					Α
Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load)	I <sub>FSM</sub>	50					А
Maximum Instantaneous Forward Voltage (at rated forward current)	$V_{F}$	0.5 0.7				V	
Maximum DC Reverse Current $T_a=25^{\circ}$ C (at rated DC blocking voltage) $T_a=100^{\circ}$ C		0.5 10.0					mA mA
Typical Junction Capacitance (Note 1)	$C_J$	200					pF
Typical Thermal Resistance (Note 2)	R <sub>θ</sub> (ja)	25					°C/W
Storage and Operation Junction Temperature	$T_{STG},T_{J}$	-65 to +150					°C

- 1.Measured at 1.0 MHz and applied voltage of 4.0V<sub>dc</sub>
- 2. Thermal resistance from junction to terminal mounted on 5×5mm copper pad area